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NPN Epitaxial Silicon Transistor

KSP44, KSP45

Features

- High–Voltage Transistor
- Collector-Emitter Voltage:
 - ◆ KSP44: V_{CEO} = 400 V
 - ◆ KSP45: V_{CEO} = 350 V
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

ABSOLUTE MAXIMUM RATINGS

Values are at $T_A = 25^{\circ}C$ unless otherwise noted.

Symbol	Parameter	Value	Unit		
V _{CBO}	Collector, Booo Voltago	KSP44	500	V	
	Collector-Base Voltage	KSP45	400		
V _{CEO}	Collector-Emitter Voltage	KSP44	400	V	
		KSP45	350		
V_{EBO}	Emitter-Base Voltage		6	V	
Ι _C	Collector Current		300	mA	
TJ	Junction Temperature		150	°C	
T _{STG}	Storage Temperature		-55 to 150	°C	

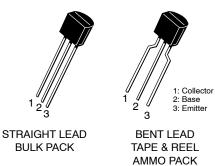
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS (Note 1)

Values are at $T_A = 25^{\circ}C$ unless otherwise noted.

Symbol	Parameter		Value	Unit
PD	Power Dissipation	$T_A = 25^{\circ}C$	625	mW
		T _C = 25°C	1.5	W
$R_{\theta JC}$	Thermal Resistance, Junction-to-Case		83.3	°C/W
R_{\thetaJA}	Thermal Resistance, Junction-to-Ambient		200	°C/W

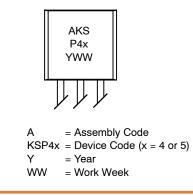
1. PCB size: FR-4, 76 mm x 114 mm x 1.57 mm (3.0 inch x 4.5 inch x 0.062 inch) with minimum land pattern size.



TO-92-3 CASE 135AN

TO-92 LF CASE 135AR

MARKING DIAGRAM



ORDERING INFORMATION

See detailed ordering and shipping information on page 2 of this data sheet.

ORDERING INFORMATION

Part Number	Top Mark	Package	Shipping [†]
KSP44BU	KSP44	TO-92-3 (Pb-Free), case 135AN	10,000 units / Bulk Bag
KSP44TA	KSP44	TO-92-3 (Pb-Free), case 135AR	2,000 units / Fan-Fold
KSP44TF	KSP44	TO-92-3 (Pb-Free), case 135AR	2,000 units / Tape & Reel
KSP45TA	KSP45	TO-92-3 (Pb-Free), case 135AR	2,000 units / Fan-Fold

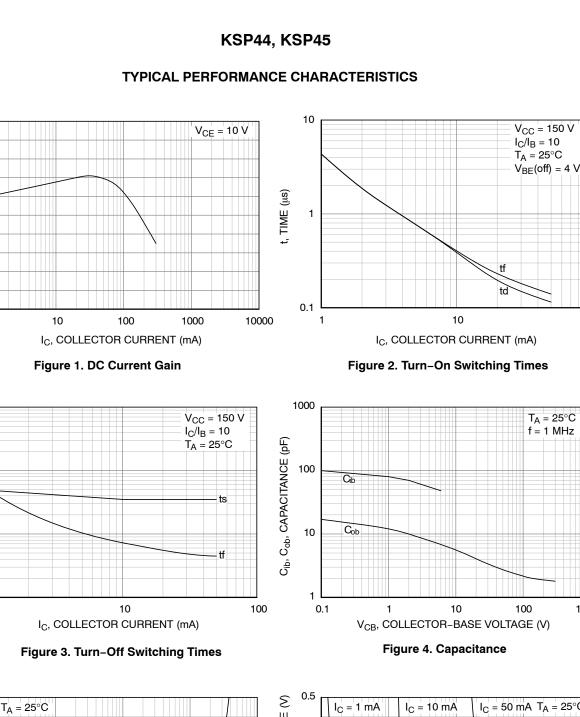
+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

ELECTRICAL CHARACTERISTICS

(Values are at $T_A = 25^{\circ}C$ unless otherwise noted.)

Symbol	Parameter		Conditions	Min.	Max.	Uni
BVana	Collector-Base Breakdown Voltage	KSP44	I _C = 100 μA, I _F = 0	500		v
BV _{CBO}	Collector-Dase Dreakdown voltage	o	400			
BV _{CEO} Collector-E (Note 2)	Collector-Emitter Breakdown Voltage	KSP44	I _C = 1 mA, I _B = 0	400		v
		KSP45	IC – 1 IIIA, IB – 0	350		v
BV_{EBO}	Emitter-Base Breakdown Voltage		$I_{E} = 100 \ \mu A, \ I_{C} = 0$	6		V
	Collector Cut-Off Current	KSP44	$V_{CB} = 400 \text{ V}, I_{E} = 0$		0.1	μΑ
I _{CBO}		KSP45	$V_{CB} = 320 \text{ V}, I_E = 0$		0.1	
I _{CES}	Collector Cut-Off Current	KSP44	$V_{CE} = 400 \text{ V}, I_{E} = 0$		0.5	μΑ
		KSP45	V _{CE} = 320 V, I _E = 0		0.5	
I _{EBO}	Emitter Cut-Off Current		$V_{EB} = 4 \text{ V}, \text{ I}_{C} = 0$		0.1	μΑ
h _{FE}	DC Current Gain (Note 2)		$V_{CE} = 10 \text{ V}, I_{C} = 1 \text{ mA}$	40		
			V _{CE} = 10 V, I _C = 10 mA	50	200	
			V _{CE} = 10 V, I _C = 50 mA	45		
			V _{CE} = 10 V, I _C = 100 mA	40		
V _{CE} (sat)	Collector-Emitter Saturation Voltage (Note 2)		I _C = 1 mA, I _B = 0.1 mA		0.40	V
			I _C = 10 mA, I _B = 1 mA		0.50	
			I _C = 50 mA, I _B = 5 mA		0.75	
V _{BE} (sat)	Base-Emitter Saturation Voltage (Note 2)		I _C = 10 mA, I _B = 1 mA		0.75	V
Cob	Output Capacitance		V _{CB} = 20 V, I _E = 0, f = 1 MHz		7	pF

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. 2. Pulse test: pulse width \leq 300 μ s, duty cycle \leq 2%.



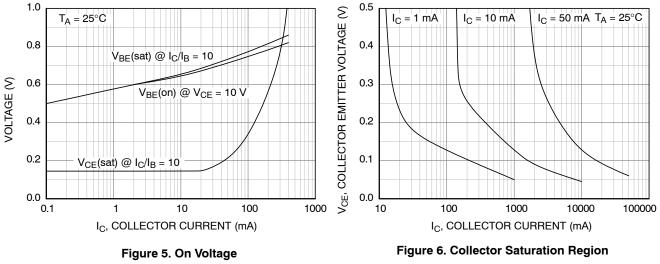
-20

-40

0.1

t, TIME (µs)

h_{FE}, DC CURRENT GAIN



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KSP44, KSP45

100000 100 V_{CE} = 10 V f = 10 MHz Valid for Duty Cycle $\leq 10\%$ h_{FE}, SMALL SIGNAL CURRENT GAIN I_C, COLLECTOR CURRENT (mA) T_A = 25°C 10000 10 1000 100us 1ms` 1s 100 $T_C = 25^{\circ}C$ 1 T_A = 25°C 10 MSPA4 1 0.1 10 10 100 1000 10000 0.1 1 100 1000 1 I_C, COLLECTOR CURRENT (mA) V_{CE}, COLLECTOR-EMITTER VOLTAGE (V)

TYPICAL PERFORMANCE CHARACTERISTICS (continued)

Figure 7. High-Frequency Current Gain

Figure 8. Safe Operating Area

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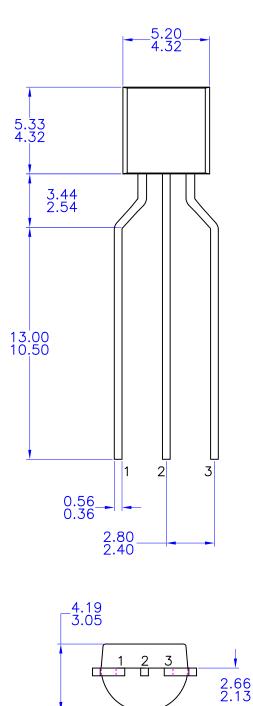
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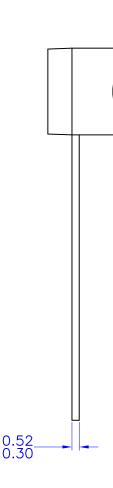
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